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# DUAL RS-232 DRIVER/RECEIVER WITH IEC61000-4-2 PROTECTION

#### **FEATURES**

- Meets or Exceeds TIA/RS-232-F and ITU Recommendation V.28
- Operates From a Single 5-V Power Supply With 1.0-μF Charge-Pump Capacitors
- · Operates up to 250 kbit/s
- Two Drivers and Two Receivers
- ±30-V Input Levels
- Low Supply Current . . . 8 mA Typical
- ESD Protection for RS-232 Bus Pins
  - ±15-kV Human-Body Model (HBM)
  - ±8-kV IEC61000-4-2, Contact Discharge
  - ±15-kV IEC61000-4-2, Air-Gap Discharge

#### **APPLICATIONS**

- TIA/RS-232-F
- Battery-Powered Systems
- Terminals
- Modems
- Computers

#### D, DW, N, NS, OR PW PACKAGE (TOP VIEW) 16**∏** Vcc. V<sub>S+</sub> [] 15 GND C1− ¶ 3 14 DOUT1 C2+ RIN1 4 13 C2- [ ROUT1 5 12 11 DIN1 V<sub>S−</sub> **[**] 6 DOUT2 17 10 DIN2 9∏ ROUT2 RIN2

#### **DESCRIPTION/ORDERING INFORMATION**

The TRS232E is a dual driver/receiver that includes a capacitive voltage generator to supply TIA/RS-232-F voltage levels from a single 5-V supply. Each receiver converts TIA/RS-232-F inputs to 5-V TTL/CMOS levels. This receiver has a typical threshold of 1.3 V, a typical hysteresis of 0.5 V, and can accept ±30-V inputs. Each driver converts TTL/CMOS input levels into TIA/RS-232-F levels. The driver, receiver, and voltage-generator functions are available as cells in the Texas Instruments LinASIC™ library.

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### ORDERING INFORMATION

T <sub>A</sub>	PA	CKAGE <sup>(1)(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 25	TRS232ECN	TRS232ECN
	SOIC – D	Tube of 40	TRS232ECD	TRS232EC
	30IC - D	Reel of 2500	TRS232ECDR	- 1K3232EC
000 to 7000	COIC DW	Tube of 40	TRS232ECDW	TDCCCCC
0°C to 70°C	SOIC – DW	Reel of 2000	TRS232ECDWR	TRS232EC
	SOP - NS	Reel of 2000	TRS232ECNSR	PREVIEW
	TCCOD DW	Tube of 25	TRS232ECPW	DUOCEC
	TSSOP – PW	Reel of 2000	TRS232ECPWR	RU32EC
	PDIP – N	Tube of 25	TRS232EIN	TRS232EIN
	COIC D	Tube of 40	TRS232EID	TDCCCCT
	SOIC – D	Reel of 2500	TRS232EIDR	TRS232EI
4000 +- 0500	COIC DW	Tube of 40	TRS232EIDW	TDCCCCT
–40°C to 85°C	SOIC – DW	Reel of 2000	TRS232EIDWR	TRS232EI
	SOP - NS	Reel of 2000	TRS232EINSR	PREVIEW
	TCCOD DW	Tube of 25	TRS232EIPW	DUIDOEL
	TSSOP – PW	Reel of 2000	TRS232EIPWR	RU32EI

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

#### **FUNCTION TABLES**

#### Each Driver<sup>(1)</sup>

INPUT DIN	OUTPUT DOUT
L	Н
Н	L

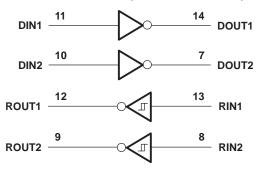
(1) H = high level, L = low level

## Each Receiver<sup>(1)</sup>

INPUT RIN	OUTPUT ROUT
L	Н
Н	L

(1) H = high level, L = low level

#### **LOGIC DIAGRAM (POSITIVE LOGIC)**



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## Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Input supply voltage range (2)		-0.3	6	V
V <sub>S+</sub>	Positive output supply voltage range		V <sub>CC</sub> - 0.3	15	V
V <sub>S-</sub>	Negative output supply voltage range		-0.3	-15	V
VI	land to take the new years	Driver	-0.3	V <sub>CC</sub> + 0.3	V
	Input voltage range	Receiver		±30	V
.,	Output well-and and and	DOUT	V <sub>S-</sub> - 0.3	V <sub>S+</sub> + 0.3	
Vo	Output voltage range	ROUT	-0.3	V <sub>CC</sub> + 0.3	V
	Short-circuit duration	DOUT		Unlimited	
		D package		73	
		DW package		57	
$\theta_{JA}$	Package thermal impedance (3)(4)	N package		67	°C/W
		NS package		64	
$\theta_{ extsf{JA}}$		PW package		108	
$T_{J}$	Operating virtual junction temperature	,		150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## **Recommended Operating Conditions**

				MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage			4.5	5	5.5	V
V <sub>IH</sub>	High-level input voltage (DIN1, DIN2)						V
V <sub>IL</sub>	Low-level input voltage (DIN1, DIN2)					0.8	V
	Receiver input voltage (RIN1, RIN2)					±30	V
_			TRS232EC	0		70	00
IA	Operating free-air temperature	-40		85	°C		

## Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

	PARAMETER	TE	ST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
Icc	Supply current	$V_{CC} = 5.5 \text{ V},$	All outputs open, T <sub>A</sub> = 25°C		8	10	mA

Test conditions are C1–C4 = 1  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V. All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.

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All voltages are with respect to network GND.

Maximum power dissipation is a function of T<sub>J</sub>(max), θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.



#### **DRIVER SECTION**

## Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature range

PARAMETER			TEST CONDITIONS			TYP <sup>(2)</sup>	MAX	UNIT
$V_{OH}$	High-level output voltage	DOUT	$R_L = 3 \text{ k}\Omega \text{ to GND}$		5	7		V
$V_{OL}$	Low-level output voltage (3)	DOUT	$R_L = 3 \text{ k}\Omega \text{ to GND}$			-7	<b>-</b> 5	V
r <sub>o</sub>	Output resistance	DOUT	$V_{S+} = V_{S-} = 0,$	V <sub>O</sub> = ±2 V	300			Ω
I <sub>OS</sub> (4)	Short-circuit output current	DOUT	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0		±10		mA
I <sub>IS</sub>	Short-circuit input current	DIN	V <sub>I</sub> = 0				200	μΑ

- (1) Test conditions are C1–C4 = 1 μF at V<sub>CC</sub> = 5 V ± 0.5 V.
  (2) All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C.
  (3) The algebraic convention, in which the least-positive (most negative) value is designated minimum, is used in this data sheet for logic voltage levels only.
- (4) Not more than one output should be shorted at a time.

# Switching Characteristics<sup>(1)</sup>

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (see Note 4)}$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Driver slew rate	$R_L = 3 \text{ k}\Omega \text{ to 7 k}\Omega$ , See Figure 2			30	V/μs
SR(t) Driver transition region slew rate		See Figure 3		3		V/μs
	Data rate	One DOUT switching		250		kbit/s

<sup>(1)</sup> Test conditions are C1–C4 = 1  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

#### **ESD** protection

PARAMETER	TYP	UNIT	
	НВМ	±15	kV
DOUT, RIN	IEC61000-4-2, Air-Gap Discharge	±15	kV
	IEC61000-4-2, Contact Discharge	±8	kV

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#### **RECEIVER SECTION**

#### Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature range

	PARAMETER			TEST CONDITIONS		TYP <sup>(2)</sup>	MAX	UNIT
$V_{OH}$	High-level output voltage	ROUT	$I_{OH} = -1 \text{ mA}$		3.5			V
$V_{OL}$	Low-level output voltage (3)	ROUT	I <sub>OL</sub> = 3.2 mA				0.4	V
V <sub>IT+</sub>	Receiver positive-going input threshold voltage	RIN	V <sub>CC</sub> = 5 V,	T <sub>A</sub> = 25°C		1.7	2.4	V
$V_{IT-}$	Receiver negative-going input threshold voltage	RIN	V <sub>CC</sub> = 5 V,	T <sub>A</sub> = 25°C	0.8	1.2		V
V <sub>hys</sub>	Input hysteresis voltage	RIN	V <sub>CC</sub> = 5 V		0.2	0.5	1	V
ri	Receiver input resistance	RIN	V <sub>CC</sub> = 5 V,	T <sub>A</sub> = 25°C	3	5	7	kΩ

## Switching Characteristics(1)

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (see Figure 1)}$ 

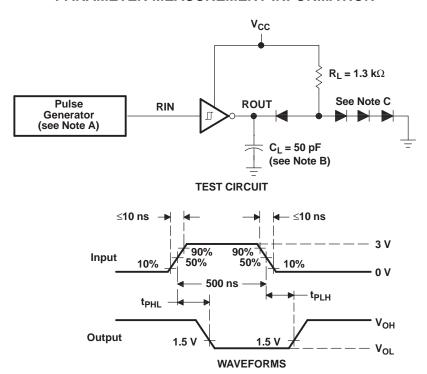
	PARAMETER	TYP	UNIT
t <sub>PLH(R)</sub>	Receiver propagation delay time, low- to high-level output	500	ns
t <sub>PHL(R)</sub>	Receiver propagation delay time, high- to low-level output	500	ns

(1) Test conditions are C1–C4 = 1  $\mu$ F at  $V_{CC}$  = 5 V ± 0.5 V.

Test conditions are C1–C4 = 1  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. All typical values are at V<sub>CC</sub> = 5 V and T<sub>A</sub> = 25°C. The algebraic convention, in which the least-positive (most negative) value is designated minimum, is used in this data sheet for logic voltage levels only.



#### PARAMETER MEASUREMENT INFORMATION

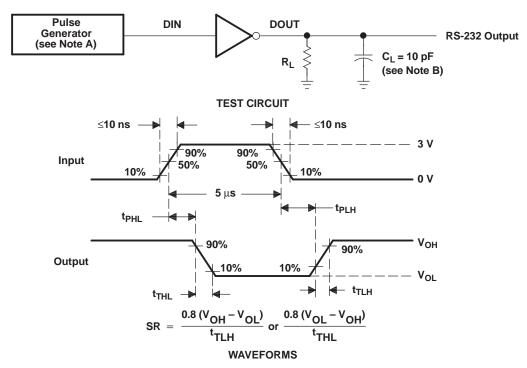


- A. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , duty cycle  $\leq 50\%$ .
- B. C<sub>L</sub> includes probe and jig capacitance.
- C. All diodes are 1N3064 or equivalent.

Figure 1. Receiver Test Circuit and Waveforms for  $t_{\text{PHL}}$  and  $t_{\text{PLH}}$  Measurements

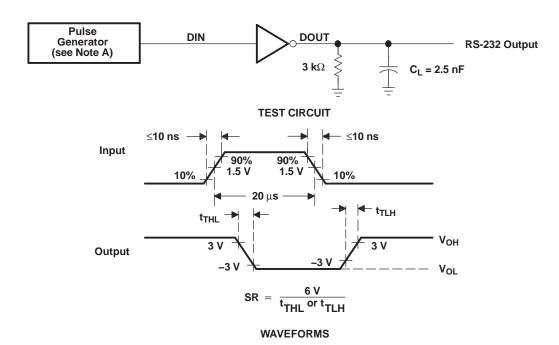


#### PARAMETER MEASUREMENT INFORMATION (continued)



- A. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , duty cycle  $\leq 50\%$ .
- B. C<sub>L</sub> includes probe and jig capacitance.

Figure 2. Driver Test Circuit and Waveforms for t<sub>PHL</sub> and t<sub>PLH</sub> Measurements (5-µs Input)

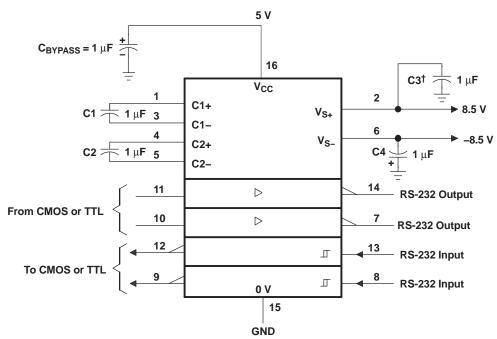


A. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , duty cycle  $\leq 50\%$ .

Figure 3. Test Circuit and Waveforms for  $t_{THL}$  and  $t_{TLH}$  Measurements (20- $\mu$ s Input)



#### **APPLICATION INFORMATION**



 $<sup>^\</sup>dagger$  C3 can be connected to  $V_{CC}$  or GND.

- A. Resistor values shown are nominal.
- B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown. In addition to the 1- $\mu$ F capacitors shown, the TRS202E can operate with 0.1- $\mu$ F capacitors.

**Figure 4. Typical Operating Circuit** 



#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TRS232ECD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TRS232ECNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TRS232ECPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232ECPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TR\$232EIN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TRS232EINE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
TRS232EIPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



#### PACKAGE OPTION ADDENDUM

22-Sep-2008

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins I	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TRS232EIPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRS232EIPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

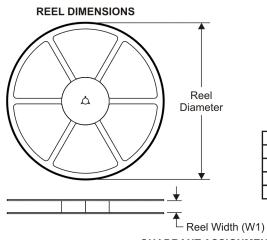
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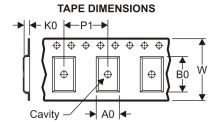
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## PACKAGE MATERIALS INFORMATION

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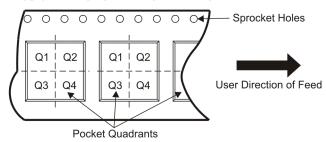
### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS232ECDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS232ECDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS232ECDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TRS232ECPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
TRS232EIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS232EIDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TRS232EIPWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS232ECDR	SOIC	D	16	2500	346.0	346.0	33.0
TRS232ECDR	SOIC	D	16	2500	333.2	345.9	28.6
TRS232ECDWR	SOIC	DW	16	2000	346.0	346.0	33.0
TRS232ECPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
TRS232EIDR	SOIC	D	16	2500	346.0	346.0	33.0
TRS232EIDWR	SOIC	DW	16	2000	346.0	346.0	33.0
TRS232EIPWR	TSSOP	PW	16	2000	346.0	346.0	29.0

#### PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

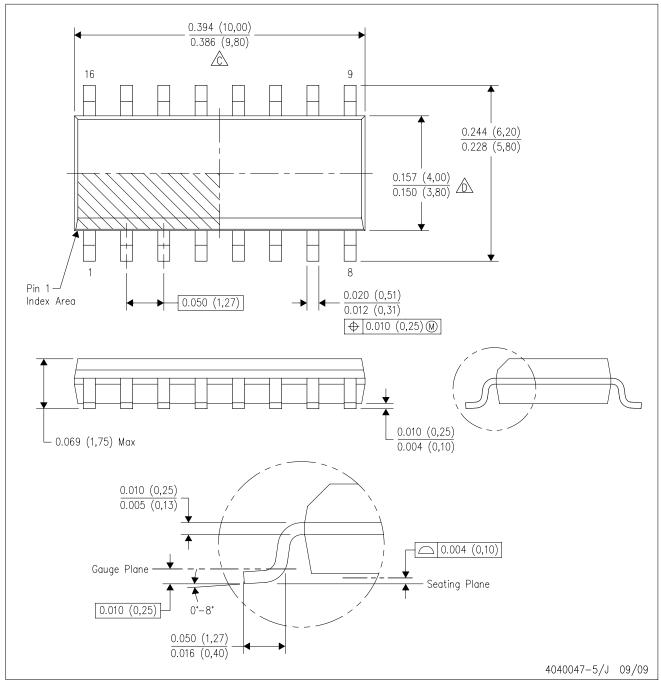
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

# D (R-PDS0-G16)

#### PLASTIC SMALL-OUTLINE PACKAGE

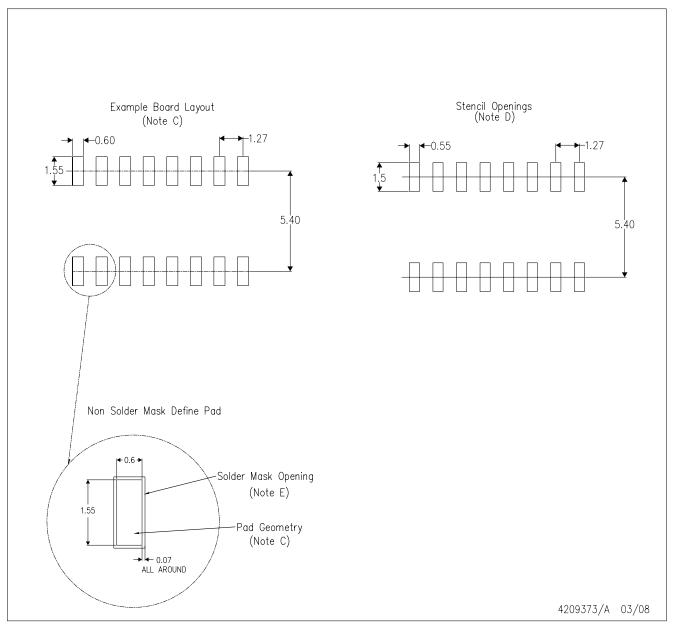


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



# D(R-PDSO-G16)



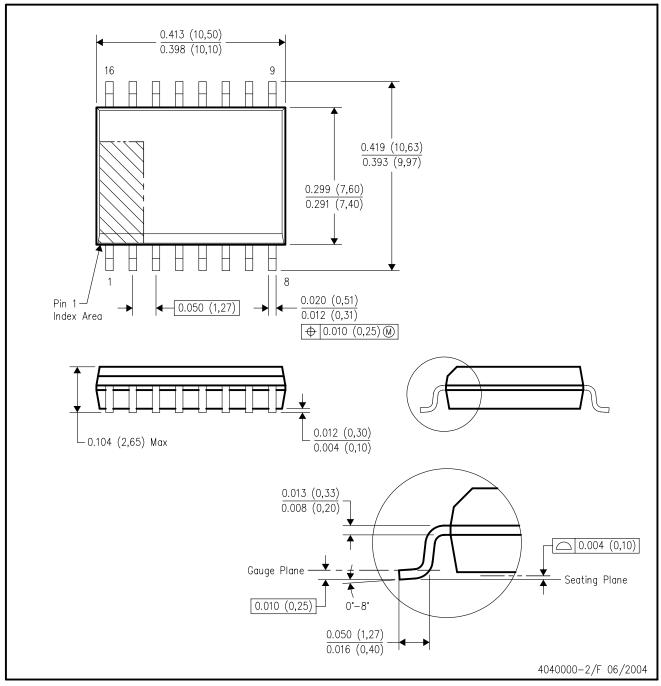
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# DW (R-PDSO-G16)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.



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